



RS1E200BNTB Information



For Reference Only

Part Number RS1E200BNTB

Manufacturer Rohm Semiconductor

Category Discrete Semiconductor Products

Transistors - FETs, MOSFETs - Single

Description MOSFET N-CH 30V 20A 8HSOP

Package 8-PowerTDFN

For the pricing/inventory/lead time, please contact

us

Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









RS1E200BNTB Specifications

Manufacturer Part Number	RS1E200BNTB
Manufacturer	Rohm Semiconductor
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	8-PowerTDFN
Series	-
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	30V
Current - Continuous Drain (Id) @ 25°C	20A (Ta)
Drive Voltage (Max Rds On, Min Rds On)	4.5V, 10V
Vgs(th) (Max) @ Id	2.5V @ 1mA
Gate Charge (Qg) (Max) @ Vgs	59nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	3100pF @ 15V
Vgs (Max)	±20V
FET Feature	-
Power Dissipation (Max)	3W (Ta), 25W (Tc)
Rds On (Max) @ Id, Vgs	3.9 mOhm @ 20A, 10V
Operating Temperature	150°C (TJ)
Mounting Type	Surface Mount
Supplier Device Package	8-HSOP
Package / Case	8-PowerTDFN
	Report errors?

RS1E200BNTB Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

RS1E200BNTB Payment Methods



















RS1E200BNTB Shipping Methods













If you have any question about RS1E200BNTB, please do not hesitate to contact us!

Website: https://www.heisener.com E-mail: salesdept@heisener.com